



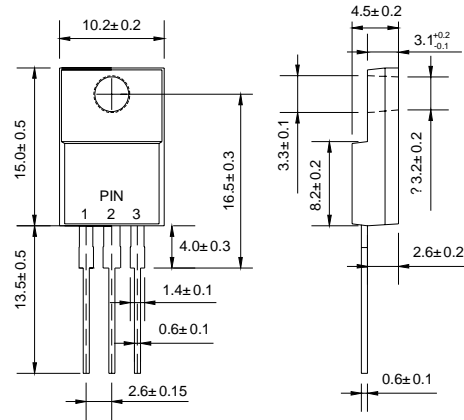
ITO-220AB

Features

- ◇ Low cost
- ◇ Diffuse junction
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

Mechanical Data

- ◇ Case: JEDEC ITO-220AB, molded plastic
- ◇ Polarity: As marked
- ◇ Weight: 0.06 ounce, 1.67grams
- ◇ Mounting position: Any



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SF 1010F C	SF 1020F C	SF 1030F C	SF 1040F C	SF 1050F C	SF 1060F C	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	300	400	500	600	V
Maximum RMS voltage	V_{RMS}	70	140	210	280	350	420	V
Maximum DC blocking voltage	V_{DC}	100	200	300	400	500	600	V
Maximum average forward rectified current @ $T_C=100^\circ\text{C}$	$I_{F(AV)}$	10						A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	I_{FSM}	60						A
Maximum instantaneous forward voltage @ 5.0A	V_F	0.98		1.3		1.7		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	I_R	5.0		10		500		μA
Maximum reverse recovery time (Note1)	t_{rr}	35						ns
Typical junction capacitance (Note2)	C_J	70		50				pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	3.0						$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ----- + 150						$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ----- + 150						$^\circ\text{C}$

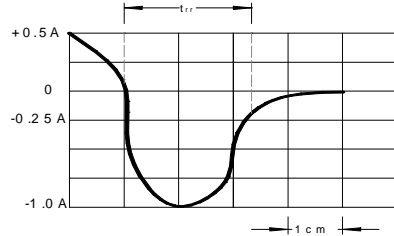
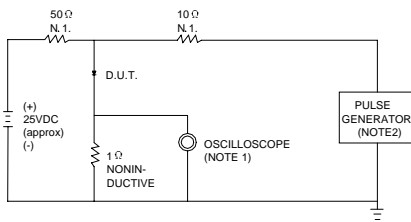
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

Ratings AND Characteristic Curves

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME = 7ns MAX. INPUT IMPEDANCE = 1MΩ .22pF.
 2. RISE TIME = 10ns MAX. SOURCE IMPEDANCE = 50Ω .

SET TIME BASE FOR 10 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

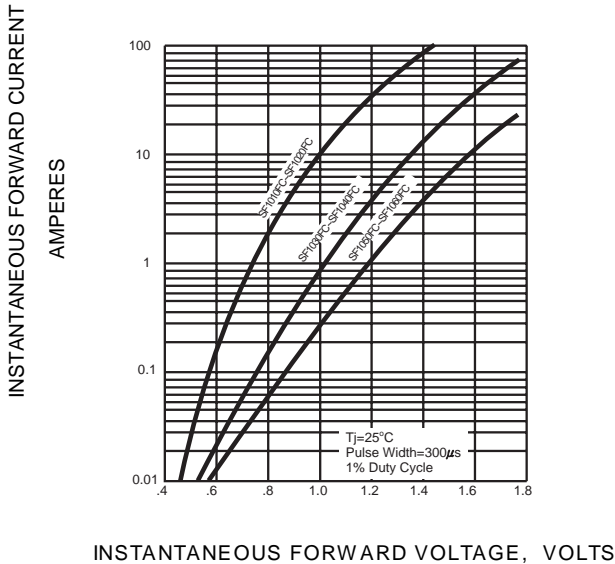


FIG.3 -- FORWARD DERATING CURVE

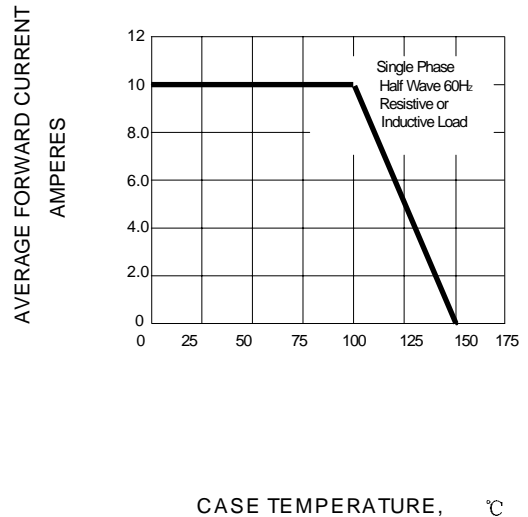


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

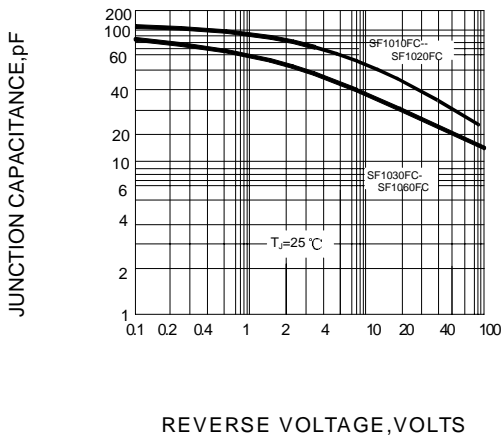


FIG.5 -- PEAK FORWARD SURGE CURRENT

